GBJ15005 THRU GBJ1510

Glass Passivated Bridge Rectifiers

Reverse Voltage - 50 to 1000 Volts Forward Current - 15 Amperes

Features

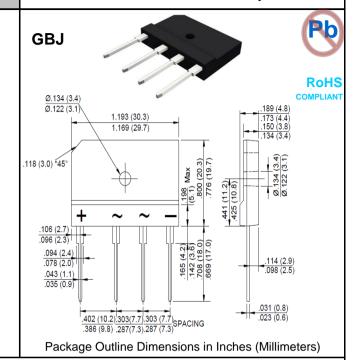
- Glass passivated chip
- Low forward voltage drop
- Ideal for printed circuit board
- High surge current capability

Mechanical Data

- Polarity: Symbol marked on body
- Mounting position: Any

Applications

 General purpose use in AC/DC bridge full wave rectification, for SMPS, lighting ballaster, adapter, etc.



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

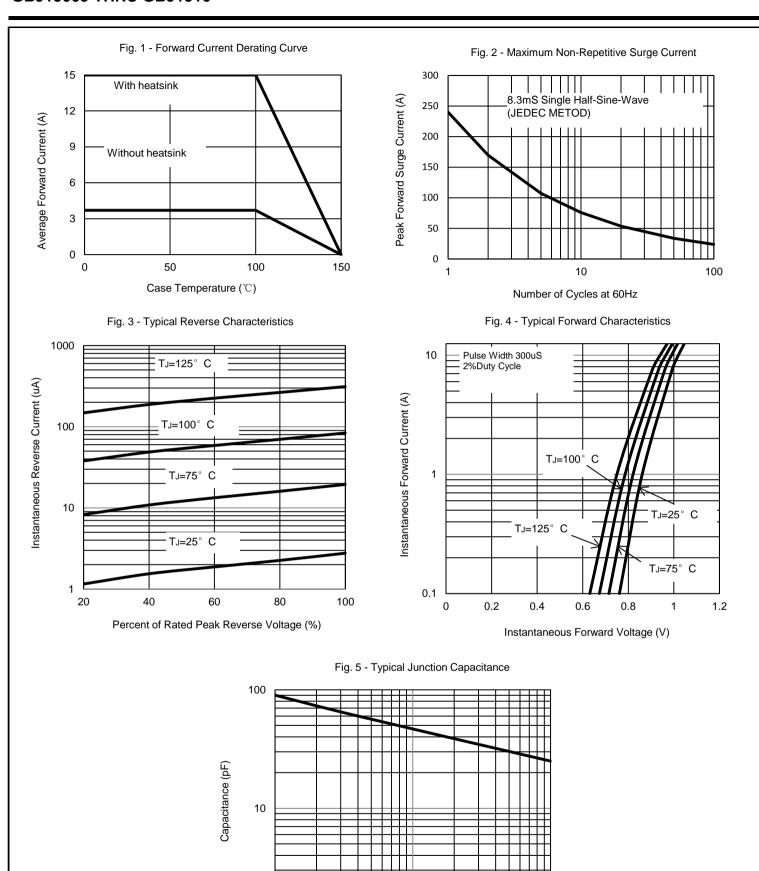
| Characteristics | Symbol | GBJ | GBJ | GBJ | GBJ | GBJ | GBJ | GBJ | Unit |
|--|------------------|---------------------|------|------|------|------|------|------------------|------------|
| | буньог | 15005 | 1501 | 1502 | 1504 | 1506 | 1508 | 1510 | 单位 |
| Maximum Repetitive Peak Reverse Voltage | VRRM | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | > |
| Maximum RMS Voltage | VRMS | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | VDC | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward (with heatsink Note 2) | I(AV) | 15.0 3.7 | | | | | | | А |
| Rectified Current @ Tc=100℃ (without heatsink) | I(AV) | | | | | | | | |
| Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, | IFSM | 240 | | | | | | | А |
| Superimposed on Rated Load (JEDEC Method) | IFSW | | | | | | | | |
| I ² t Rating for Fusing (t<8.3mS) | l ² t | 240 | | | | | | A ² s | |
| Peak Forward Voltage per Diode at 7.5A DC | VF | 1.0 | | | | | | | V |
| Maximum DC Reverse Current at Rated @TJ=25°C | lr | 5.0 500 | | | | | | | μА |
| DC Blocking Voltage per Diode @TJ=125℃ | IK . | | | | | | | | |
| Typical Junction Capacitance per Diode (Note1) | Cı | 60 | | | | | | | pF |
| Typical Thermal Resistance to Ambient (Note2) | Reja | RejA 4.5 RejC 0.8 | | | | | | | °C/W |
| Typical Thermal Resistance to case (Note2) | Rejc | | | | | | | | |
| Typical Thermal Resistance to lead (Note2) | Røjl | 1.5 | | | | | | | |
| Operating Junction Temperature Range | TJ | -55 to +150 | | | | | | | $^{\circ}$ |
| Storage Temperature Range | Тѕтс | -55 to +150 | | | | | | | $^{\circ}$ |
| | | | | | | | | | • |

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2.Device mounted on 300mm*300mm*1.6mm Cu plate heatsink.

3. The typical data above is for reference only

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TJ=25° C,f=1MHz

10 Reverse Voltage (V)

The curve above is for reference only.

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